

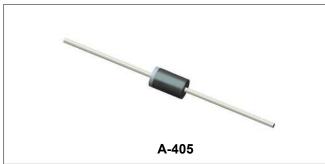




# **RL101F THRU RL107F**

#### **FAST RECOVERY RECTIFIERS**

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere



#### **Features**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- · Fast switching for high efficiency
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 260 C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Mechanical Data**

- Case: A-405 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.008 ounce, 0.23 grams

### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	RL 101F	RL 102F	RL 103F	RL 104F	RL 105F	RL 106F	RL 107F	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at T <sub>A</sub> =75℃	I <sub>(AV)</sub>	1.0			Α				
Peak forward surge current 8.3ms single half sinewave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30			А				
Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>	1.3			V				
Maximum DC reverse current $T_A$ =25 $^{\circ}$ C at rated DC blocking voltage $T_A$ =100 $^{\circ}$ C	I <sub>R</sub>	5.0 50.0			μA				
Maximum Reverse Recovery Time (Note 1)	Trr		1:	50		250	5	00	ns
Typical Junction Capacitance (Note 2)	Сл	15.0			pF				
Typical Thermal Resistance (Note 3)	R <sub>θJA</sub>	50.0			°C/W				
Junction Temperature	TJ	-65 to +150			°C				
Storage Temperature Range	T <sub>STG</sub>	-65 to +150		°C					

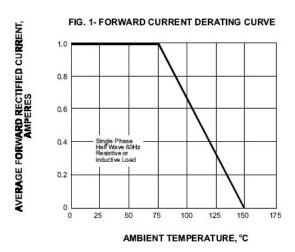
- Note: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A
  - 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
  - 3. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted
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### **Ratings and Characteristics Curves**



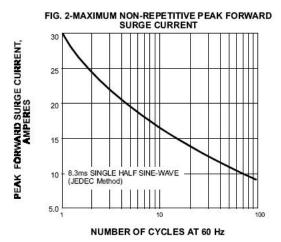
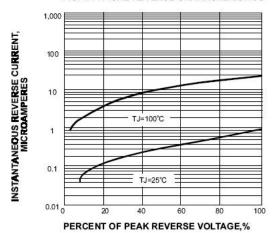


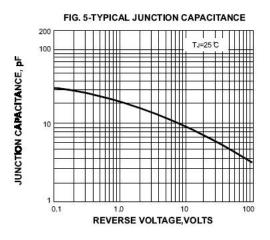
FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

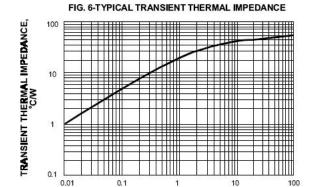
20
10
10
TJ=25°C
PULSE WIDTH=300 µS
1%DTY CYCLE
1%DTY CYCLE
1,4 1.5





INSTANTANEOUS FORWARD VOLEAGE, VOLTS





t,PULSE DURATION,sec.

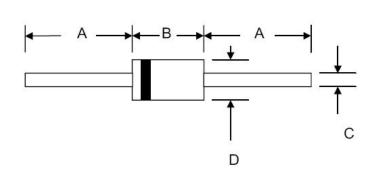
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#### **Mechanical Dimensions A-405**



SYMBOL	Millin	neters	Inches			
OTMBOL	Min.	Max.	Min.	Max.		
А	25.4	-	1.000	-		
В	4.20	5.20	0.166	0.205		
С	0.55	0.65	0.021	0.025		
D	2.00	2.70	0.080	0.107		

### **Ordering Information**

Device	Package	Shipping		
RL101F-RL107F	A-405 (Pb-Free)	5000pcs /tape		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



Where XXXXX is YYWWL

 RL101F
 = Part Name

 SSG
 = SSG

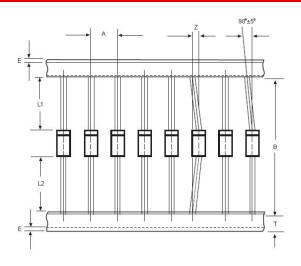
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Carrier Tape Specification A-405**



SYMBOL	Millimeters			
	Min.	Max.		
А	4.50	5.50		
В	25.3	25.5		
Z	1.20	1.30		
Т	5.5	6.5		
E	-	0.80		
IL1-L2I	-	1.0		

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